

Substitute for form 1449A/PTO

Complete if Known

**INFORMATION DISCLOSURE
STATEMENT BY APPLICANT**

(Use as many sheets as necessary)

Application Number	10/607,769
Filing Date	June 27, 2003
First Named Inventor	Hareland, Scott A.
Group Art Unit	2891
Examiner Name	Such, Matthew W.

Sheet 1 of 7

Attorney Docket No: 42P15685

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Sheet 2 of 7

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Sheet 3 of 7	Attorney Docket No: 42P15685	

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